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3/9/1

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Positive pole for lithium sec. cell for power source of small and light wt. el comprising material contg. at least lithium is vapour deposited on electrode, oxide film contg. lithium-oxide formed on substrate

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Patent Family:

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JP 8287901	A	19961101	JP 9593860	A	19950419	199703 B

Priority Applications (No Type Date): JP 9593860 A 19950419

Patent Details:

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JP 8287901	A	6	H01M-004/04	

Abstract (Basic): JP 8287901 A

Method comprises: (a) a material contg. at least Li is vapour deposited on an electrode substrate and simultaneously ions are irradiated on the substrate; and (b) an oxide film contg. at least Li-oxide is formed on the substrate by blowing O₂ on the substrate.

USE - The cell is suitable for power source of smaller size and light wt. electronic appts..

ADVANTAGE - The electrode has improved property since adhesiveness of the oxide film with the electrode substrate is improved.

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Title Terms: POSITIVE; POLE; LITHIUM; SEC; CELL; POWER; SOURCE; LIGHT; WEIGHT; ELECTRONIC; APPARATUS; COMPRISE; MATERIAL; CONTAIN; LITHIUM; VAPOUR; DEPOSIT; ELECTRODE; SUBSTRATE; OXIDE; FILM; CONTAIN; LITHIUM; OXIDE; FORMING; SUBSTRATE

Derwent Class: L03; X16

International Patent Class (Main): H01M-004/04

International Patent Class (Additional): C23C-014/22

File Segment: CPI; EPI

Manual Codes (CPI/A-N): L03-E01B5

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